

# E-paper Display Series

GDEY027T91**-T01** 

Dalian Good Display Co., Ltd.





## **Product Specifications**

Customer	Standard			
Description	2.7" E-PAPER DI SPLAY			
Model Name	GDEY027T91 <b>-T01</b>			
Date	2022/10/10			
Revision	1.0			

Design Engineering				
Approval Check Design				
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## **REVISION HISTORY**

Rev	Date	Item	Page	Remark
1.0	Oct.10.2022	New Creation	ALL	



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## 1. Over View

GDEY027T91-T01 is an Active Matrix Electrophoretic Display (AM EPD), with interface and a reference system design. The display is capable to display image at 1-bit white, black full display capabilities. The 2.7inch active area contains 264×176pixels. The module is a TFT-array driving electrophoresis display, with integrated circuits including gate driver, source driver, MCU interface, timing controller, oscillator, DC-DC, SRAM, LUT , VCOM. Module can be used in portable electronic devices, such as Electronic Shelf Label (ESL) System.

## 2.Features

264×176 pixels display with touchscreen High cntrast High reflectance Ultra wide viewing angle Ultra low power consumption Pure reflective mode Bi-stable display Commercial temperature range Landscape portrait modes Hard-coat antiglare display surface Ultra Low current deep sleep mode On chip display RAM Waveform can stored in On-chip OTP or written by MCU

Serial peripheral interface available

On-chip oscillator

On-chip booster and regulator control for generating VCOM, Gate and Source driving voltage

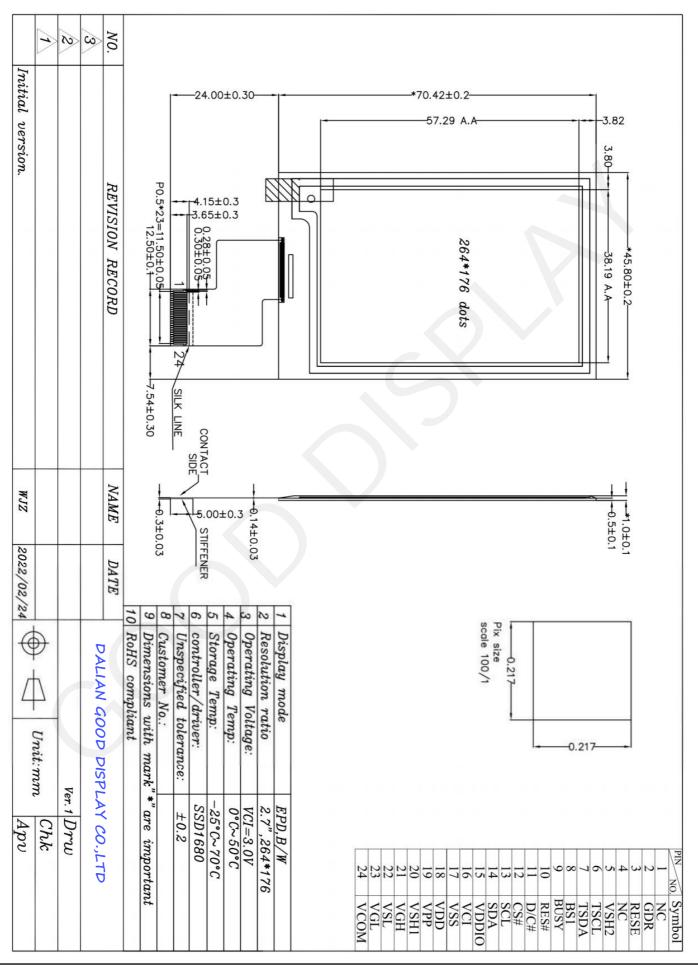
I2C signal master interface to read external temperature sensor Built-in temperature sensor

Parameter	Specifications	Unit	Remark
Screen Size	2.7	Inch	
Display Resolution	264(H)×176(V)	Pixel	Dpi:117
Active Area	38.19×57.29	mm	
Pixel Pitch	0.217×0.217	mm	
Pixel Configuration	Rectangle		
Outline Dimension	45.8 (H)×70.42(V) ×1.23(D)	mm	
Weight	TBD	g	

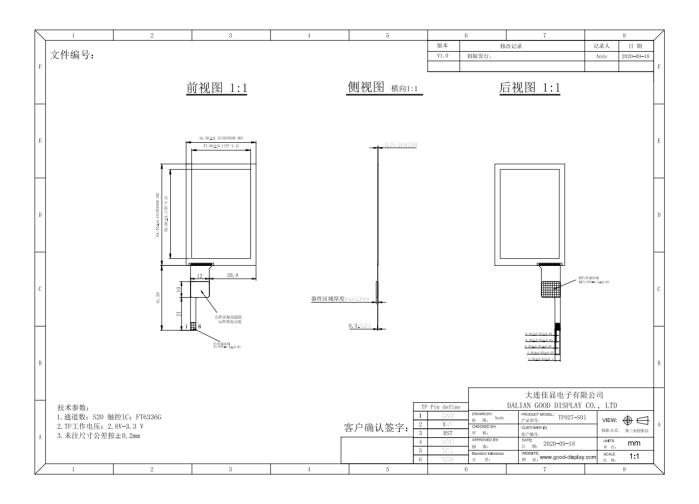
### **3.Mechanical Specifications**

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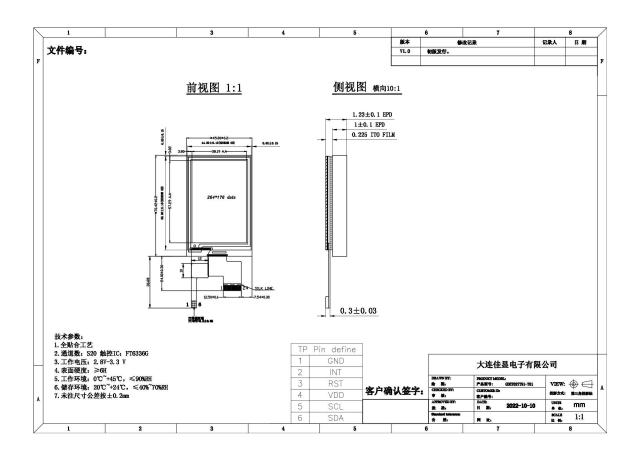
## 4. Mechanical Drawing of EPD module



## 4.1 Mechanical Drawing of TP027-S01



## 4.2 Mechanical Drawing of GDEY027T91-T01



## **5. Input /Output Pin Assignment**

No.	Name	I/O	Description	Remark
1	NC		Do not connect with other NC pins	Keep Open
2	GDR	0	N-Channel MOSFET Gate Drive Control	
3	RESE	Ι	Current Sense Input for the Control Loop	
4	NC	NC	Do not connect with other NC pins	Keep Open
5	VSH2	С	Positive Source driving voltage(Red)	
6	TSCL	0	I <sup>2</sup> C Interface to digital temperature sensor Clock pin	
7	TSDA	I/O	I <sup>2</sup> C Interface to digital temperature sensor Data pin	
8	BS1	Ι	Bus Interface selection pin	Note 5-5
9	BUSY	0	Busy state output pin	Note 5-4
10	RES#	Ι	Reset signal input. Active Low.	Note 5-3
11	D/C#	Ι	Data /Command control pin	Note 5-2
12	CS#	Ι	Chip select input pin	Note 5-1
13	SCL	Ι	Serial Clock pin (SPI)	
14	SDA	Ι	Serial Data pin (SPI)	
15	VDDIO	Р	Power Supply for interface logic pins It should be connected with VCI	
16	VCI	Р	Power Supply for the chip	
17	VSS	Р	Ground	
18	VDD	С	Core logic power pin VDD can be regulated internally from VCI. A capacitor should be connected between VDD and VSS	
19	VPP	Р	FOR TEST	
20	VSH1	C	Positive Source driving voltage	
21	VGH	С	Power Supply pin for Positive Gate driving voltage and VSH1	
22	VSL	С	Negative Source driving voltage	
23	VGL	С	Power Supply pin for Negative Gate driving voltage VCOM and VSL	
24	VCOM	С	VCOM driving voltage	

I = Input Pin, O =Output Pin, I/O = Bi-directional Pin (Input/output), P = Power Pin, C = Capacitor Pin

**Note 5-1:** This pin (CS#) is the chip select input connecting to the MCU. The chip is enabled for MCU communication only when CS# is pulled LOW.

**Note 5-2:** This pin is (D/C#) Data/Command control pin connecting to the MCU in 4-wire SPI mode. When the pin is pulled HIGH, the data at SDA will be interpreted as data. When the pin is pulled LOW, the data at SDA will be interpreted as command.

Note 5-3: This pin (RES#) is reset signal input. The Reset is active low.

**Note 5-4:** This pin is Busy state output pin. When Busy is High, the operation of chip should not be interrupted, command should not be sent. The chip would put Busy pin High when –Outputting display waveform -Communicating with digital temperature sensor

Note 5-5: Bus interface selection pin

BS1 State	MCU Interface
L	4-lines serial peripheral interface(SPI) - 8 bits SPI
Н	3- lines serial peripheral interface(SPI) - 9 bits SPI

### 6. Electrical Characteristics 6.1 Absolute Maximum Rating

Parameter	Symbol	Rating	Unit
Logic supply voltage	VCI	-0.5 to +6.0	V
Logic Input voltage	VIN	-0.5 to VCI +0.5	V
Logic Output voltage	VOUT	-0.5 to VCI +0.5	V
Operating Temp range	TOPR	0 to +50	°C
Storage Temp range	TSTG	-25 to+70	°C
Optimal Storage Temp	TSTGo	23±2	°C
Optimal Storage Humidity	HSTGo	55±10	%RH

### Note:

Maximum ratings are those values beyond which damages to the device may occur. Functional operation should be restricted to the limits in the Panel DC Characteristics tables.

## 6.2 Panel DC Characteristics

The following specifications apply for: VSS=0V, VCI=3.0V, TOPR =25°C.

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Parameter	Symbol	Conditions	Applica ble pin	Min.	Тур.	Max	Units
Single ground	V <sub>ss</sub>			-	0	-	V
Logic supply voltage	V <sub>CI</sub>		VCI	2.2	3.0	3.7	V
Core logic voltage	V <sub>DD</sub>		VDD	1.7	1.8	1.9	V
High level input voltage	V <sub>IH</sub>	-		0.8 V <sub>CI</sub>	-	_	V
Low level input voltage	V <sub>IL</sub>	-		_	-	0.2 V <sub>CI</sub>	V
High level output voltage	V <sub>OH</sub>	IOH = - 100uA		0.9 VCI	-	-	V
Low level output voltage	V <sub>OL</sub>	IOL = 100uA			-	0.1 V <sub>CI</sub>	V
Typical power	Р <sub>ТУР</sub>	V <sub>CI</sub> =3.0V			TBD		mW
Deep sleep mode	P <sub>STPY</sub>	V <sub>CI</sub> =3.0V		(	0.003		mW
Typical operating current	Iopr_V <sub>CI</sub>	V <sub>CI</sub> =3.0V		-	TBD		mA
Full update time		25 °C			3		sec
Fast update time	-	25 °C			1.5		sec
Partial update time		25 °C			0.42		sec
Sleep mode current	Islp_V <sub>CI</sub>	DC/ DC off No clock No input load Ram data retain		<u> </u>	20		uA
Deep sleep mode current	Idslp_V <sub>CI</sub>	DC/ DC off No clock No input load Ram data not retain	-	-	1	5	uA

Notes:

1) Refresh time: the time it takes for the whole process from the screen change to the screen stabilization.

2) The difference between different refresh methods:

Full refresh: The screen will flicker several times during the refresh process;

Fast Refresh: The screen will flash once during the refresh process;

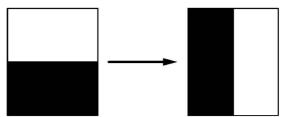
Partial refresh: The screen does not flicker during the refresh process.

During the fast refresh or partial refresh of the electronic paper, it is recommended to add a full-screen refresh after 5 consecutive operations to reduce the accumulation of afterimages on the screen.

1. The typical power is measured with following transition from horizontal 2 scale pattern to vertical 2 scale pattern.

2. The deep sleep power is the consumed power when the panel controller is in deep sleep mode.

3. The listed electrical/optical characteristics are only guaranteed under the controller & waveform provided by GOOD DISPLAY.



## **6.3 Panel AC Characteristics**

## 6.3.1 MCU Interface Selection

MCU interface is pin selectable by BS1 shown in Table 6-1.

Table 6-1 : Interface pins assignment under different MCU interface

	Pin Name					
MCU Interface	BS1	RES#	CS#	D/C#	SCL	SDA
4-wire serial peripheral interface (SPI)	L	RES#	CS#	DC#	SCL	SDA
3-wire serial peripheral interface (SPI) – 9 bits SPI	Н	RES#	CS#	L	SCL	SDA

Note : (1) L is connected to VSS and H is connected to VDDIO

## 6.3.2 MCU Serial Interface (4-wire SPI)

The 4-wire SPI consists of serial clock SCL, serial data SDA, D/C# and CS#. The control pins status in 4-wire SPI in writing command/data is shown in Table 6-2 and the write procedure 4-wire SPI is shown in Table 6-2

Function	SCL pin	SDA pin	D/C# pin	CS# pin
Write command	↑	Command bit	L	L
Write data	<b>↑</b>	Data bit	Н	L

Table 6-2 : Control pins status of 4-wire SPI

Note: (1) L is connected to VSS and H is connected to VDDIO

(2) ↑ stands for rising edge of signal

(3) SDA (Write Mode) is shifted into an 8-bit shift register on every rising edge of SCL in the order of D7, D6, ... D0. The level of D/C# should be kept over the whole byte. The data byte in the shift register is written to the Graphic Display Data RAM (RAM)/Data Byte register or command Byte register according to D/C# pin.

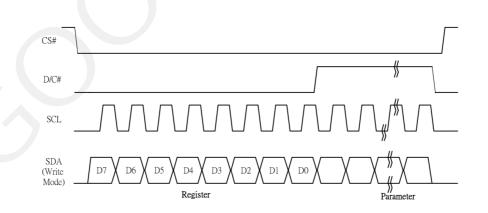


Figure 6-1 : Write procedure in 4-wire SPI mode

In the read operation (Command 0x1B, 0x27, 0x2D, 0x2E, 0x2F, 0x35). After CS # is pulled low, the first byte sent is command byte, D/C# is pulled low. After com mand byte sent, the following byte(s) read are data byte(s), so D/C# bit is then pu lled high. An 8-bit data will be shifted out on every clock falling edge. The serial da ta SDA bit shifting sequence is D7, D6, to D0 bit. Figure 6-2 shows the read procedure in 4-wire SPI.

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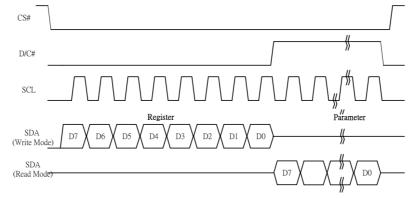


Figure 6-2 : Read procedure in 4-wire SPI mode

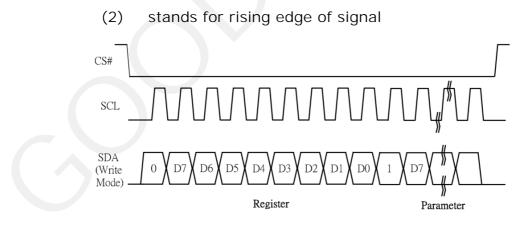
## 6.3.3 MCU Serial Interface (3-wire SPI)

The 3-wire SPI consists of serial clock SCL, serial data SDA and CS#. The operation is similar to 4-wire SPI while D/C# pin is not used and it must be tied to LOW. The control pins status in 3-wire SPI is shown in Table 6-3.

In the write operation, a 9-bit data will be shifted into the shift register on every clock rising edge. The bit shifting sequence is D/C# bit, D7 bit, D6 bit to D0 bit. The first bit is D/C# bit which determines the following byte is command or data. When D/C# bit is 0, the following byte is command. When D/C# bit is 1, the following byte is data. Table 6-3 shows the write procedure in 3-wire SPI

Function	SCL pin	SDA pin	D/C# pin	CS# pin
Write command	↑	Command bit	Tie LOW	L
Write data	$\uparrow$	Data bit	Tie LOW	L

Note: (1) L is connected to VSS and H is connected to VDDIO



#### Figure 6-3 : Write procedure in 3-wire SPI

In the read operation (Register 0x1B, 0x27, 0x2D, 0x2E, 0x2F, 0x35). SDA data are transferred in the unit of 9 bits. After CS# pull low, the first byte is command by te, the D/C# bit is as 0 and following with the register byte. After command byte send, the following byte(s) are data byte(s), with D/C# bit is 1.After D/C# bit sending from MCU, an 8-bit data will be shifted out on every clock falling edge. The serial data SDA bit shifting sequence is D7, D6, to D0 bit. Figure 6-4 shows the read procedure in 3-wire SPI.



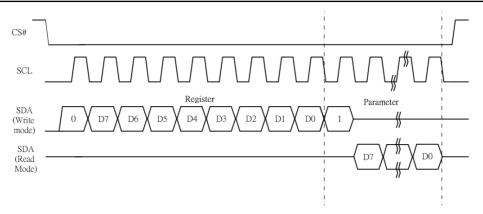


Figure 6-4 : Read procedure in 3-wire SPI mode

## 6.3.4 Interface Timing

The following specifications apply for: VDDIO - VSS = 2.2V to 3.7V, CL=20pF

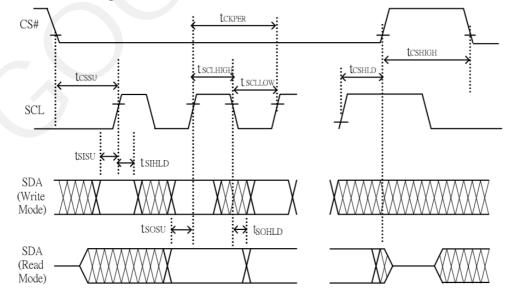
#### Write mode

Parameter	Min	Тур	Max	Unit
SCL frequency (Write Mode)	-	-	20	MHz
Time CS# has to be low before the first rising edge of SCLK	60		-	ns
Time CS# has to remain low after the last falling edge of SCLK	65	920	5423	ns
Time CS# has to remain high between two transfers	100	270		ns
Part of the clock period where SCL has to remain high	25	( <b>-</b> 3)		ns
Part of the clock period where SCL has to remain low	25	-		ns
Time SI (SDA Write Mode) has to be stable before the next rising edge of SCL	10	1.00	1.00	ns
Time SI (SDA Write Mode) has to remain stable after the rising edge of SCL	40	-	-	ns
	SCL frequency (Write Mode)         Time CS# has to be low before the first rising edge of SCLK         Time CS# has to remain low after the last falling edge of SCLK         Time CS# has to remain high between two transfers         Part of the clock period where SCL has to remain high         Part of the clock period where SCL has to remain low         Time SI (SDA Write Mode) has to be stable before the next rising edge of SCL	SCL frequency (Write Mode)       -         Time CS# has to be low before the first rising edge of SCLK       60         Time CS# has to remain low after the last falling edge of SCLK       65         Time CS# has to remain high between two transfers       100         Part of the clock period where SCL has to remain high       25         Part of the clock period where SCL has to remain low       25         Time SI (SDA Write Mode) has to be stable before the next rising edge of SCL       10	SCL frequency (Write Mode)-Time CS# has to be low before the first rising edge of SCLK60Time CS# has to remain low after the last falling edge of SCLK65Time CS# has to remain high between two transfers100Part of the clock period where SCL has to remain high25Part of the clock period where SCL has to remain low25Time SI (SDA Write Mode) has to be stable before the next rising edge of SCL10	SCL frequency (Write Mode)-20Time CS# has to be low before the first rising edge of SCLK60-Time CS# has to remain low after the last falling edge of SCLK65-Time CS# has to remain high between two transfers100-Part of the clock period where SCL has to remain high25-Part of the clock period where SCL has to remain low25-Time SI (SDA Write Mode) has to be stable before the next rising edge of SCL10-

#### Read mode

Symbol	Parameter	Min	Тур	Max	Unit
fscl	SCL frequency (Read Mode)	-	(12)	2.5	MHz
tcssu	Time CS# has to be low before the first rising edge of SCLK	100	1	10	ns
t <sub>CSHLD</sub>	Time CS# has to remain low after the last falling edge of SCLK	50	275	3 <del>7</del> 0	ns
t <sub>cshigh</sub>	Time CS# has to remain high between two transfers	250	-	1940	ns
tsclhigh	Part of the clock period where SCL has to remain high	180		10	ns
tscllow	Part of the clock period where SCL has to remain low	180	200	38	ns
tsosu	Time SO(SDA Read Mode) will be stable before the next rising edge of SCL	-	50	-	ns
t <sub>SOHLD</sub>	Time SO (SDA Read Mode) will remain stable after the falling edge of SCL		0	(577)	ns

Note: All timings are based on 20% to 80% of VDDIO-VSS



## 7. Command Table

om	D/C#	Hex	D7	D6	D5	D4	D3	D2	D1	DO	Command	Descripti	on		
0	0	01	0	0	0	0	0	0	0	1	Driver Output control	Gate setti			
1227	1.1.1	UI	-	1100	205	1.00	12	1000	12	254				], 296 MU	х
0	1		A <sub>7</sub>	A <sub>6</sub>	A <sub>5</sub>	A <sub>4</sub>	A <sub>3</sub>	A <sub>2</sub>	A <sub>1</sub>	A <sub>0</sub>	-			tting as (A	
0	1		0	0	0	0	0	0	0	A <sub>8</sub>	-				aan ad ji
0	1		0	0	0	0	0	B <sub>2</sub>	Bı	Bo				]. uence and	I directior
												B[2]: GD Selects th GD=0 [PC	DR],		
												output see GD=1,	quence is	G0,G1, G	2, G3,
														G1, G0, C	
														order of ga	te driver.
												SM=0 [PC	DR],	172	
												G0, G1, G		95 (left an	na right ga
												SM=1,	1		
													64G29	4, G1, G3	,G29
														n from G0 G295 to G	
											1	16			
0	0	03	0	0	0	0	0	0	1	1	Gate Driving voltage	Set Gate			
0	1		0	0	0	A <sub>4</sub>	A <sub>3</sub>	A <sub>2</sub>	A <sub>1</sub>	Ao	Control	A[4:0] = 0			,
														0V to 20V	
												A[4:0] 00h	VGH 20	A[4:0] 0Dh	VGH 15
												03h	10	0Eh	15.5
												04h	10.5	0Fh	16
												05h	11	10h	16.5
												06h	11.5	11h	17
												07h	12	12h	17.5
												08h	12.5	13h	18
												07h	12	14h	18.5
												08h	12.5	15h	19
												09h	13	16h	19.5
												0Ah	13.5	17h	20
												0Bh	14	Other	NA
											1	0Ch	14.5		

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W#	D/C#	Hex	D7	D6	D5	D4	D3	D2	D1	DO	Comm	nand		Description
0	0	04	0	0	0	0	0	1	0	0	Contraction of the	e Driving	voltage	Set Source driving voltage
-	0.72	04	10101	0000	00	02061	50001	172	1090	112	Contro		voltage	A[7:0] = 41h [POR], VSH1 at 15V
0	1		A7	A <sub>6</sub>	A5	A4	A <sub>3</sub>	A <sub>2</sub>	A1	Ao	Contre			B[7:0] = A8h[POR], VSH2 at 5V.
0	1		B <sub>7</sub>	B <sub>6</sub>	B <sub>5</sub>	B <sub>4</sub>	B <sub>3</sub>	B <sub>2</sub>	B <sub>1</sub>	Bo				C[7:0] = 32h [POR], VSL at -15V
0	1		C7	C <sub>6</sub>	C <sub>5</sub>	C <sub>4</sub>	C <sub>3</sub>	C <sub>2</sub>	C1	C <sub>0</sub>	]			Remark: VSH1>=VSH2
17	/B[7]	= 1							7]/B[7		1			C[7] = 0,
/Sł	H1/VS 8.8V	SH2	voltag	je se	tting	from	2.4V	VS				e setting	from 9V	
	B[7:0]	VSH	1/VSH2	A/E	8[7:0]	VSH1	/VSH2		A/B[7:0]	VS	H1/VSH2	A/B[7:0]	VSH1/VSH2	2 C[7:0] VSL
1211	8Eh	10.000	2.4	S	Fh	5	5.7		23h		9	3Ch	14	0Ah -5
12	8Fh		2.5	B	lOh	5	i.8		24h		9.2	3Dh	14.2	0Ch -5.5
_	90h	1.1	2.6		1h		5.9		25h	_	9.4	3Eh	14.4	0Eh -6
_	91h		2.7		l2h I3h		6		26h	_	9.6	3Fh 40h	14.6	10h -6.5
	92h 93h	-	2.8 2.9	-	ian I4h		5.1 5.2	1	27h 28h	-	9.8 10	40n 41h	14.8 15	12h -7
_	93n 94h	-	3	2 3	5h		5.2 5.3	-	20h		10.2	41h 42h	15.2	14h -7.5
_	95h		3.1		l6h		5.4		2Ah	-	10.4	43h	15.4	16h -8
	96h	1	3.2	B	7h	6.5		2Bh			10.6	44h	15.6	18h -8.5
_	97h		3.3	(Y)	18h	100	6.6	15	2Ch		10.8	45h	15.8	1Ah -9
_	98h		3.4	-	19h		6.7		2Dh		11	46h	16	1Ch -9.5
_	99h		3.5	BAh BBh		850	8.0	_	2Eh	-	11.2	47h	16.2	1Eh -10
	9Ah 9Bh		3.6 3.7		Bh Ch		5.9 7		2Fh 30h	-	11.4	48h 49h	16.4 16.6	20h -10.5
	9Dh	-	3.8	-	Dh	<u> </u>	7. [1]	-	31h	+	11.8	49h	16.8	- 22h -11
_	9Dh		3.9	1.1	Eh		.2		32h		12	4Bh	17	24h -11.5
1	9Eh		4	BFh		7.3			33h		12.2	Other	NA	26h -12
	9Fh		4.1	C0h C1h		7.4		34h			12.4			28h -12.5
_	A0h		4.2				.5	0	35h		12.6			2Ah -13
	A1h A2h		4.3 4.4	C2h C3h		7.6		1	36h 37h	+	12.8			2Ch -13.5
	A2h A3h	1.00	12.9%	C4h		7.7		-	3/h 38h	+	13			2Eh -14
	A4h		4.6 C5h			7.8			395	+	13.4			30h -14.5
_	A5h		4.7 C6h			8		-	3Ah	-	13.6			
	A6h	4.8 C7h		8.1		-	3Bh		13.8			34h -15.5		
18	A7h		4.9	C	8h	h 8.2				- 1				36h -16
	A8h		5	-	9h		.3							38h -16.5
	A9h		5.1		Ah		3.4							3Ah -17
	AAh ABh	-	5.2 5.3	2 A	8h Ch		1.5 1.6							Other NA
_	ACh		5.4	1 10	Dh		.7							
_	ADh		5.5	1. 123	Eh	-	.8							
2	AEh	1	5.6	0	ther	١	NA .							
)	0	08	0	0	0	0	1	0	0	0	Initial (	Code Set	ting	Program Initial Code Setting
								~				Program		- regram milder oods ootting
												- egi alti		The command required CLKEN=1. Refer to Register 0x22 for detail.
														BUSY pad will output high during operation.
)	0	09	0	0	0	0	1	0	0	1			for Initial	Write Register for Initial Code Setting
)	1		A <sub>7</sub>	A <sub>6</sub>	A <sub>5</sub>	A4	A <sub>3</sub>	A <sub>2</sub>	A <sub>1</sub>	A	Code	Setting		Selection
)	1		B <sub>7</sub>	B <sub>6</sub>	B <sub>5</sub>	B <sub>4</sub>	B <sub>3</sub>	B <sub>2</sub>	B <sub>1</sub>	Bo	1			A[7:0] ~ D[7:0]: Reserved
	- 12 - L			1000	1.110.000	0.4124.2			personal second	10.000				Details refer to Application Notes of Initia
)	1		<b>C</b> <sub>7</sub>	C <sub>6</sub>	C <sub>5</sub>	C <sub>4</sub>	C <sub>3</sub>	C <sub>2</sub>	C <sub>1</sub>	C <sub>0</sub>	-			Code Setting
C	1		D <sub>7</sub>	D <sub>6</sub>	D <sub>5</sub>	D <sub>4</sub>	D <sub>3</sub>	D <sub>2</sub>	D <sub>1</sub>	Do				
0	0	0A	0	0	0	0	1	0	1	0		Register Setting	for Initial	Read Register for Initial Code Setting

## 🗗 GooDisplay

	man		12122				1	-	1.000	Terrer	-		N
	D/C#		D7	D6	D5	D4	D3	D2	D1	DO	Command	Description	
0	0	0C	0	0	0	0	1	1	0	0	Booster Soft start Control		e with Phase 1, Phase 2 and Phase 3 urrent and duration setting.
0	1		1	A <sub>6</sub>	A <sub>5</sub>	A4	A <sub>3</sub>	A <sub>2</sub>	A1	Ao		A[7:0] > Coff.	start setting for Phase1
0	1		1	B <sub>6</sub>	B <sub>5</sub>	B <sub>4</sub>	B <sub>3</sub>	B <sub>2</sub>	B <sub>1</sub>	B <sub>0</sub>			Bh [POR]
0	1		1	C <sub>6</sub>	C <sub>5</sub>	C <sub>4</sub>	C <sub>3</sub>	C <sub>2</sub>	C <sub>1</sub>	C <sub>0</sub>	_		start setting for Phase2 Ch [POR]
0	1		0	0	D5	D4	D <sub>3</sub>	D2	D1	Do		C[7:0] -> Soft	start setting for Phase3
												= 96 D[7:0] -> Dura	Sh [POR]
													Th [POR]
													ription of each byte: 3[6:0] / C[6:0]:
												Bit[6:4]	Driving Strength Selection
												000	1(Weakest)
												001	2
												010	3
												011	4
												100	5
												101	6
												110	7
												111	8(Strongest)
												Bit[3:0]	Min Off Time Setting of GDR [ Time unit ]
												0000	Contract Contract
												0011	NA
												0100	2.6
												0101	3.2
												0110	3.9
												0111	4.6
												1000	5.4
												1001	6.3
												1010	7.3
											· ·	1011	8.4
								K -				1100	9.8
												1101	11.5
												1110	13.8
										1		1111	16.5
												D[5:4]: D[3:2]:	uration setting of phase duration setting of phase 3 duration setting of phase 2 duration setting of phase 1 Duration of Phase [Approximation]
												00	10ms
						1						01	20ms
												10	30ms
				7								11	40ms
)	0	10	0	0	0	1	0	0	0	0	Deep Sleep mode	Deep Slee	p mode Control:
0	1	10	0	0	0	0	0	0	A1	A	Book cleek mode	A[1:0] :	Description
U	1		0	U	0	U	0	U	A	AO		00	Normal Mode [POR]
												01	Enter Deep Sleep Mode 1
												11	Enter Deep Sleep Mode 2
													command initiated, the chip
												enter Dee keep outp Remark:	p Sleep Mode, BUSY pad wi ut high.
													ep Sleep mode, User requir
												to send H	WRESET to the driver

## 🗗 GooDisplay

	man	and an other states of						-		-		la contraction de la contracti
	D/C#		D7	D6	D5	D4	D3	D2	D1	DO	Command	Description
0	0	11	0	0	0	1	0	0	0	1	Data Entry mode setting	Define data entry sequence A[2:0] = 011 [POR]
0	1		0	0	0	0	0	A2	Aı	Ao		A[2:0] = 011 [POR] A [1:0] = ID[1:0] Address automatic increment / decrement setting The setting of incrementing or decrementing of the address counter car be made independently in each upper and lower bit of the address. 00 –Y decrement, X decrement, 01 –Y decrement, X decrement, 10 –Y increment, X decrement, 11 –Y increment, X increment [POR] A[2] = AM Set the direction in which the address counter is updated automatically after data are written to the RAM. AM= 0, the address counter is updated in the X direction. [POR] AM = 1, the address counter is updated in the Y direction.
0	0	12	0	0	0	1	0	0	1	0	SW RESET	It resets the commands and parameters to their S/W Reset default values except R10h-Deep Sleep Mode During operation, BUSY pad will output high. Note: RAM are unaffected by this command.
0	0	14	0	0	0	1	0	1	0	0	HV Ready Detection	HV ready detection A[7:0] = 00h [POR] The command required CLKEN=1 and ANALOGEN=1. Refer to Register 0x22 for detail. After this command initiated, HV Ready detection starts. BUSY pad will output high during detection. The detection result can be read from the Status Bit Read (Command 0x2F).
0	1		0	A6	A5	A4	0	A <sub>2</sub>	Aı	Ao		A[6:4]=n for cool down duration: 10ms x (n+1) A[2:0]=m for number of Cool Down Loop to detect. The max HV ready duration is 10ms x (n+1) x (m) HV ready detection will be trigger after each cool down time. The detection will be completed when HV is ready. For 1 shot HV ready detection, A[7:0] can be set as 00h.

## 🕒 GooDisplay

	man D/C#	the second second	D7	D6	D5	D4	D3	D2	D1	DO	Command	Description
_						10 700 0						
0	0	15	0	0	0	1 0	0	1 A2	0 A1	1 A <sub>0</sub>	VCI Detection	VCI Detection A[2:0] = 100 [POR] , Detect level at 2.3V A[2:0] : VCI level Detect
												A[2:0] VCI level
												011 2.2V
												100 2.3V
												101 2.4V
												110 2.5V
												111 2.6V
												Other NA
0 0	0 1 0 1 1	18 1A	0 A7 0 A7	0 A6 A6	0 A5 0 A5	1 A4 1 A4	1 A3 1 A3	0 A2 0 A2	0 A1 1 A1	0 Ao 0 Ao	Temperature Sensor Control Temperature Sensor Control (Write to temperature register)	The command required CLKEN=1 and ANALOGEN=1 Refer to Register 0x22 for detail. After this command initiated, VCI detection starts. BUSY pad will output high during detection. The detection result can be read from the Status Bit Read (Command 0x2F). Temperature Sensor Selection A[7:0] = 48h [POR], external temperatrure sensor A[7:0] = 80h Internal temperature sensor Write to temperature register. A[7:0] = 7Fh [POR]
0	0	1B	0	0	0	1	1	0	1	1	Temperature Sensor	Read from temperature register.
1	1		A7	A <sub>6</sub>	A5	A4	Аз	A <sub>2</sub>	A1	Ao	Control (Read from temperature register)	
0	0	1C	0	0	0	1	1	1	0	0	Temperature Sensor	Write Command to External temperature
0	1		A <sub>7</sub>	A <sub>6</sub>	A <sub>5</sub>	A <sub>4</sub>	A <sub>3</sub>	A <sub>2</sub>	A <sub>1</sub>	A <sub>0</sub>	Control (Write Command	sensor. A[7:0] = 00h [POR],
0	1		B7	B6	B <sub>5</sub>	B4	B <sub>3</sub>	B <sub>2</sub>	B1	Bo	to External temperature sensor)	B[7:0] = 00h [POR],
0	1		C7	C <sub>6</sub>	C <sub>5</sub>	C4	C <sub>3</sub>	C <sub>2</sub>	C <sub>1</sub>	Co		$C[7:0] = 00h [POR],$ $A[7:6]$ $A[7:6] Select no of byte to be sent$ $00 Address + pointer$ $01 Address + pointer + 1st parameter$ $10 Address + pointer + 1st parameter + 2nd pointer$ $11 Address$ $A[5:0] - Pointer Setting$ $B[7:0] - 1^{st} parameter$
												C[7:0] – 2 <sup>nd</sup> parameter The command required CLKEN=1. Refer to Register 0x22 for detail. After this command initiated, Write Command to external temperature sensor starts. BUSY pad will output high during operation.
0	0	1F	0	0	0	1	1	1	1	1	IC revision Read	Read IC revision [POR 0x0D]
1000			A <sub>7</sub>	A	A <sub>5</sub>	A4	A <sub>3</sub>	A <sub>2</sub>	A <sub>1</sub>	Ao		



	man		ble		1							
R/W#	D/C#	Hex	D7	D6	D5	D4	D3	D2	D1	DO	Command	Description
0	0	20	0	0	1	0	0	0	0	0	Master Activation	Activate Display Update Sequence The Display Update Sequence Option is located at R22h. BUSY pad will output high during operation. User should not interrupt this operation to avoid corruption of panel images.
0	0	04	0	0		0	0	0			District Control	
0	0	21	0	0	1	0	0	0	0	1	Display Update Control	RAM content option for Display Update A[7:0] = 00h [POR]
0	1		A7	A <sub>6</sub>	A <sub>5</sub>	A4	A <sub>3</sub>	A2	A1	Ao		B[7:0] = 00h [POR]
0	1		B <sub>7</sub>	0	0	0	0	0	0	0		A[7:4] Red RAM option         0000       Normal         0100       Bypass RAM content as 0         1000       Inverse RAM content         A[3:0] BW RAM option       0000         0000       Normal         0100       Bypass RAM content as 0         1000       Inverse RAM content         B[7] Source Output Mode       0         0       Available Source from S0 to S175         1       Available Source from S8 to S167
0	0	24	0	0	1	0	0	1	0	0	Write RAM (Black White) / RAM 0x24	After this command, data entries will be written into the BW RAM until another command is written. Address pointers w advance accordingly For Write pixel: Content of Write RAM(BW) = 1 For Black pixel: Content of Write RAM(BW) = 0

	man D/C#		D7	D6	D5	D4	D3	D2	D1	DO	Command	Description	
0	0	22	0	0	1	0	0	0	1	0	Display Update	Display Update Sequence Opti	on:
0	1		A <sub>7</sub>	A <sub>6</sub>	A <sub>5</sub>	A <sub>4</sub>	A <sub>3</sub>	A <sub>2</sub>	A <sub>1</sub>	A <sub>0</sub>	Control 2	Enable the stage for Master Ac A[7:0]= FFh (POR)	
												Operating sequence	Parameter (in Hex)
												Enable clock signal	80
												Disable clock signal	01
												Enable clock signal	
												→ Enable Analog	C0
												Disable Analog	03
										Disable clock signal	101010		
												Enable clock signal → Load LUT with DISPLAY Mode 1 → Disable clock signal	91
												Pisable clock signal     Enable clock signal     → Load LUT with DISPLAY Mode 2     → Disable clock signal	99
												Enable clock signal → Load temperature value → Load LUT with DISPLAY Mode 1	B1
												Disable clock signal	-
												Enable clock signal     A clock signal     A clock signal	Carlor -
												Load LUT with DISPLAY Mode 2     Disable clock signal	B9
												Enable clock signal	2
												Enable Analog     Display with DISPLAY Made 4	07
										<ul> <li>Display with DISPLAY Mode 1</li> <li>Disable Analog</li> </ul>	C7		
				Disable OSC      Enable clock signal	→ Disable OSC	-							
												Enable clock signal → Enable Analog	
												<ul> <li>Display with DISPLAY Mode 2</li> </ul>	CF
								→ Disable Analog → Disable OSC					
												Enable clock signal	
												→ Enable Analog → Load temperature value	
												DISPLAY with DISPLAY Mode 1	F7
												→ Disable Analog → Disable OSC	
												Enable clock signal	
												→Enable Analog	
												➔ Load temperature value ➔ DISPLAY with DISPLAY Mode 2	FF
												→ Disable Analog	
												Disable OSC	
0	0	26	0	0	1	0	0	1	1	0	Write RAM (RED) / RAM 0x26	After this command, data entrie written into the RED RAM until command is written. Address p	another
												advance accordingly.	
			×									For Red pixel:	
												Content of Write RAM(RED) =	
												For non-Red pixel [Black or Wh	
				u – 1								Content of Write RAM(RED) =	= 0
0	0	27	0	0	1	0	0	1	1	1	Read RAM	After this command, data read	on the
			- 1996					~1				MCU bus will fetch data from R According to parameter of Reg	RAM. ister 41h
												to select reading RAM0x24/ RA until another command is writte	
												Address pointers will advance	л <b>.</b> .
												accordingly.	
												The 1 <sup>st</sup> byte of data read is dur	nmy data.

	and the second second	Hex	1000	D6	D5	D4	D3	D2	D1	DO	Command	Descript	tion		
												-			
0	0	28	0	0	1	0	1	0	0	0	VCOM Sense	for durat VCOM v The sen register The com ANALOC Refer to	ion defined value. sed VCOM mmand requ GEN=1 Register 0 ad will outp	d in 29h b I voltage uired CLM x22 for d	
							2 22 31				1				
0	0	29	0	0	1	0	1	0	0	1	VCOM Sense Duration				ing VCOM
0	1		0	1	0	0	A <sub>3</sub>	A <sub>2</sub>	A1	Ao		A[3:0] =	mode and 9h, duratic sense dura	on = 10s.	acquired. 3:0]+1) sec
0	0	2A	0	0	1	0	1	0	1	0	Program VCOM OTP	Program	VCOM re	aister into	OTP
												Refer to	nmand requ Register 0 ad will outp n.	x22 for d	etail.
0	0	2C	0 A7	0 A6	1 A5	0 A4	1 A3	1 A2	0 A1	0 A0	Write VCOM register		COM regist 00h [POR]		ICU interface
												A[7:0]	VCOM	A[7:0]	VCOM
												08h	-0.2	44h	-1.7
												0Ch	-0.3	48h	-1.8
											1	10h	-0.4	4Ch	-1.9
												14h	-0.5	50h	-2
												18h	-0.6	54h	-2.1
												1Ch	-0.7	58h	-2.2
												20h	-0.8	5Ch	-2.3
												24h	-0.9	60h	-2.4
												28h	-1	64h	-2.5
												2Ch	-1.1	68h	-2.6
												30h	-1.2	6Ch	-2.7
												34h	-1.3	70h	-2.8
												38h			
												38h 3Ch	-1.4 -1.5	74h 78h	-2.9 -3

		d Ta	1000					-			1	
121-1	D/C#	100.000	D7	D6	D5	D4	D3	D2	D1	D0	Command	Description
0	0	2D	0	0	1	0	1	1	0	1	OTP Register Read for	Read Register for Display Option:
1	1		A7	A <sub>6</sub>	A <sub>5</sub>	A <sub>4</sub>	A <sub>3</sub>	A <sub>2</sub>	A1	A <sub>0</sub>	Display Option	A[7:0]: VCOM OTP Selection
1	1		B <sub>7</sub>	B <sub>6</sub>	B <sub>5</sub>	B <sub>4</sub>	B <sub>3</sub>	B <sub>2</sub>	B <sub>1</sub>	Bo		(Command 0x37, Byte A)
1	1		<b>C</b> <sub>7</sub>	C <sub>6</sub>	<b>C</b> 5	C <sub>4</sub>	C <sub>3</sub>	<b>C</b> <sub>2</sub>	C <sub>1</sub>	C <sub>0</sub>		
1	1		D <sub>7</sub>	D <sub>6</sub>	D <sub>5</sub>	D4	D <sub>3</sub>	D <sub>2</sub>	D <sub>1</sub>	D <sub>0</sub>		B[7:0]: VCOM Register
1	1		E <sub>7</sub>	E <sub>6</sub>	E <sub>5</sub>	E4	E <sub>3</sub>	E <sub>2</sub>	E <sub>1</sub>	E <sub>0</sub>		(Command 0x2C)
1	1		F <sub>7</sub>	F <sub>6</sub>	F <sub>5</sub>	F <sub>4</sub>	F <sub>3</sub>	F <sub>2</sub>	F <sub>1</sub>	Fo		C[7:0]~G[7:0]: Display Mode
1	1		G <sub>7</sub>	G <sub>6</sub>	G <sub>5</sub>	G <sub>4</sub>	G <sub>3</sub>	G <sub>2</sub>	G <sub>1</sub>	G <sub>0</sub>		(Command 0x37, Byte B to Byte F)
1	1		H <sub>7</sub>	H <sub>6</sub>	H <sub>5</sub>	H <sub>4</sub>	H <sub>3</sub>	H <sub>2</sub>	H <sub>1</sub>	Ho		[5 bytes]
1	1		17	16	15	4	13	<b>l</b> 2	1	lo		H[7:0]~K[7:0]: Waveform Version
1	1		J <sub>7</sub>	J <sub>6</sub>	J <sub>5</sub>	J4	J <sub>3</sub>	J <sub>2</sub>	J <sub>1</sub>	Jo		(Command 0x37, Byte G to Byte J)
1	1		K <sub>7</sub>	K <sub>6</sub>	K <sub>5</sub>	K <sub>4</sub>	K <sub>3</sub>	K <sub>2</sub>	K <sub>1</sub>	K <sub>0</sub>		[4 bytes]
											1	
0	0	2E	0	0	1	0	1	1	1	0	User ID Read	Read 10 Byte User ID stored in OTP:
1	1		A <sub>7</sub>	A <sub>6</sub>	A <sub>5</sub>	A <sub>4</sub>	A <sub>3</sub>	A <sub>2</sub>	A <sub>1</sub>	A		A[7:0]]~J[7:0]: UserID (R38, Byte A and
1	1		B <sub>7</sub>	B <sub>6</sub>	B <sub>5</sub>	B <sub>4</sub>	B <sub>3</sub>	B <sub>2</sub>	B <sub>1</sub>	B <sub>0</sub>		Byte J) [10 bytes]
1	1		C <sub>7</sub>	C <sub>6</sub>	<b>C</b> 5	C <sub>4</sub>	C <sub>3</sub>	C <sub>2</sub>	C <sub>1</sub>	C <sub>0</sub>		
1	1		D <sub>7</sub>	D <sub>6</sub>	D <sub>5</sub>	D <sub>4</sub>	D <sub>3</sub>	D <sub>2</sub>	D <sub>1</sub>	D <sub>0</sub>		
1	1		E7	E <sub>6</sub>	E <sub>5</sub>	E4	E <sub>3</sub>	E <sub>2</sub>	E1	E <sub>0</sub>		
1	1		F <sub>7</sub>	F <sub>6</sub>	F <sub>5</sub>	F <sub>4</sub>	F <sub>3</sub>	F <sub>2</sub>	F <sub>1</sub>	Fo		
1	1		G7	G <sub>6</sub>	G <sub>5</sub>	G4	G <sub>3</sub>	G <sub>2</sub>	G1	Go		
1	1		H <sub>7</sub>	H <sub>6</sub>	H <sub>5</sub>	H <sub>4</sub>	H <sub>3</sub>	H <sub>2</sub>	H <sub>1</sub>	Ho		
1	1		17	<b>l</b> 6	15	4	13	12	11	lo		
1	1		J <sub>7</sub>	J <sub>6</sub>	J <sub>5</sub>	J4	J <sub>3</sub>	J <sub>2</sub>	J <sub>1</sub>	Jo		
0	0	2F	0	0	1	0	1	1	1	1	Status Bit Read	Read IC status Bit [POR 0x01]
1	1	21	0	0	A5	A4	0	0	A1	Ao		A[5]: HV Ready Detection flag [POR=0] 0: Ready
												1: Not Ready A[4]: VCI Detection flag [POR=0]
												0: Normal 1: VCI lower than the Detect level
												A[3]: [POR=0]
												A[2]: Busy flag [POR=0]
												0: Normal 1: BUSY
												A[1:0]: Chip ID [POR=01]
												Remark:
												A[5] and A[4] status are not valid after RESET, they need to be initiated by
												command 0x14 and command 0x15
												respectively.
0	0	30	0	0	1	1	0	0	0	0	Program WS OTP	Program OTP of Waveform Setting The contents should be written into RAM before sending this command.
												The command required CLKEN=1.
												Refer to Register 0x22 for detail. BUSY pad will output high during operation.

	man		-				1.1.1.1.1	-	-	1.745.95	1-	
R/W#	D/C#	Hex	D7	D6	D5	D4	D3	D2	D1	DO	Command	Description
0	0	31	0	0	1	1	0	0	0	1	Load WS OTP	Load OTP of Waveform Setting The command required CLKEN=1. Refer to Register 0x22 for detail.
												BUSY pad will output high during operation.
0	0	32	0	0	1	1	0	0	1	0	Write LUT register	Write LUT register from MCU interface
0	1	52	A7	A6	A <sub>5</sub>	A <sub>4</sub>	A <sub>3</sub>	A <sub>2</sub>	A <sub>1</sub>	A	VIIIe LOT Tegister	[227 bytes], which contains the content of
0	1	2	B7	Be	B5	B4	B3	B <sub>2</sub>	B1	Bo	-	VS[nX-LUTm], TP[nX], RP[n], SR[nXY],
0	1		:	:	:	:	:	:	:	:	-	FR and XON[nXY] Refer to Session 6.7 WAVEFORM
0	1		(141)			•			*			SETTING
					1						na 1911 - Tarana Angela ang ang ang ang ang ang ang ang ang an	
0	0	34	0	0	1	1	0	1	0	0	CRC calculation	CRC calculation command For details, please refer to SSD1680A application note.
												BUSY pad will output high during operation.
0	0	35	0	0	1	1	0	1	0	1	CRC Status Read	CRC Status Read
1	1		A15	A14	A13	A <sub>12</sub>	A11	A10	Ag	A <sub>8</sub>		A[15:0] is the CRC read out value
1	1		A <sub>7</sub>	A	A <sub>5</sub>	A <sub>4</sub>	A <sub>3</sub>	A <sub>2</sub>	A <sub>1</sub>	A <sub>0</sub>		
0	0	36	0	0	1	1	0	1	1	0	Program OTP selection	Program OTP Selection according to the OTP Selection Control [R37h and R38h]
												The command required CLKEN=1. Refer to Register 0x22 for detail. BUSY pad will output high during operation.
0		07	0				•					
0	0	37	0 A7	0	1	1	0	1	1	1	Option	Write Register for Display Option A[7] Spare VCOM OTP selection
0	1	-	B7	B6	B <sub>5</sub>	B <sub>4</sub>	B3	B <sub>2</sub>	B1	Bo		0: Default [POR]
0	1	-	C7	C <sub>6</sub>	C <sub>5</sub>	C4	C <sub>3</sub>	C <sub>2</sub>	C1	Co	-	1: Spare
0	1		D7	D <sub>6</sub>	D <sub>5</sub>	D <sub>4</sub>	D <sub>3</sub>	D <sub>2</sub>	D <sub>1</sub>	D <sub>0</sub>	-	B[7:0] Display Mode for WS[7:0]
0	1		E7	E <sub>6</sub>	E <sub>5</sub>	E4	E <sub>3</sub>	E <sub>2</sub>	E1	E <sub>0</sub>	-	C[7:0] Display Mode for WS[15:8]
0	1		0	F <sub>6</sub>	0	0	F3	F2	F1	Fo		D[7:0] Display Mode for WS[23:16] 0: Display Mode 1
0	1		G7	G <sub>6</sub>	G <sub>5</sub>	G <sub>4</sub>	G <sub>3</sub>	G <sub>2</sub>	G <sub>1</sub>	G <sub>0</sub>		1: Display Mode 2
0	1		H <sub>7</sub>	H <sub>6</sub>	H <sub>5</sub>	H <sub>4</sub>	H <sub>3</sub>	H <sub>2</sub>	H <sub>1</sub>	Ho		F[6]: Ping-Pong for Display Mode 2
0	1		17	6	15	14	13	12	11	lo		F[6]: Ping-Pong for Display Mode 2 0: RAM Ping-Pong disable [POR]
0	1		J7	J <sub>6</sub>	J <sub>5</sub>	J4	J <sub>3</sub>	J <sub>2</sub>	J <sub>1</sub>	Jo		1: RAM Ping-Pong enable G[7:0]~J[7:0] module ID /waveform
												version.
												Remarks: 1) A[7:0]~J[7:0] can be stored in OTP 2) RAM Ping-Pong function is not suppor for Display Mode 1

	man D/C#			D6	D5	D4	D3	D2	D1	D0	Command	Description	(	
0	0	38	0	0	1	1	1	0	0	0	Write Register for User ID			
0	1	30	11118		1.11			0.512		Ao			:0]: UserID [10 bytes]	
1000	100		A <sub>7</sub>	A <sub>6</sub>	A <sub>5</sub>	A <sub>4</sub>	A <sub>3</sub>	A <sub>2</sub>	A <sub>1</sub>	10.00	-	, drien of		
0	1		B <sub>7</sub>	B <sub>6</sub>	B <sub>5</sub>	B <sub>4</sub>	B <sub>3</sub>	B <sub>2</sub>	B <sub>1</sub>	Bo			[7:0]~J[7:0] can be stored in	
0	1		C <sub>7</sub>	C <sub>6</sub>	C <sub>5</sub>	C <sub>4</sub>	C <sub>3</sub>	C <sub>2</sub>	C <sub>1</sub>	C <sub>0</sub>	-	OTP		
0	1		D <sub>7</sub>	D <sub>6</sub>	D <sub>5</sub>	D <sub>4</sub>	D <sub>3</sub>	D <sub>2</sub>	D <sub>1</sub>	D <sub>0</sub>	-			
0	1		E7	E <sub>6</sub>	E <sub>5</sub>	E <sub>4</sub>	E <sub>3</sub>	E <sub>2</sub>	E <sub>1</sub>	E <sub>0</sub>				
0	1		F <sub>7</sub>	F <sub>6</sub>	F <sub>5</sub>	F <sub>4</sub>	F <sub>3</sub>	F <sub>2</sub>	F <sub>1</sub>	Fo				
0	1		G <sub>7</sub>	G <sub>6</sub>	G <sub>5</sub>	G <sub>4</sub>	G <sub>3</sub>	G <sub>2</sub>	G <sub>1</sub>	G <sub>0</sub>				
0	1		H <sub>7</sub>	H <sub>6</sub>	H <sub>5</sub>	H <sub>4</sub>	H <sub>3</sub>	H <sub>2</sub>	H <sub>1</sub>	Ho				
0	1		17	6	15	14	13	12	11	lo				
0	1		J <sub>7</sub>	J <sub>6</sub>	J <sub>5</sub>	J4	J <sub>3</sub>	J <sub>2</sub>	J <sub>1</sub>	Jo				
0	0	39	0	0	1	1	1	0	0	1	OTP program mode	OTP program	m mode	
0	1		0	0	0	0	0	0	A <sub>1</sub>	A		A[1:0] = 00: A[1:0] = 11: programmin : User is req	Normal Mode [POR] Internal generated OTP	
0	0	3C	0	0	1	1	1	1	0	0	Border Waveform Control	Select borde	er waveform for VBD	
0	1		<b>A</b> 7	A <sub>6</sub>	A5	A <sub>4</sub>	0	0	A1	Ao		A[7:0] = C0h [POR], set VBD as HIZ A [7:6] :Select VBD option		
												A[7:6]	Select VBD as	
												00	GS Transition, Defined in A[2] and A[1:0] Fix Level,	
													Defined in A[5:4]	
												10	VCOM	
												11[POR]	HiZ	
													evel Setting for VBD VBD level	
												A[5:4]	VSS	
												01	VSB VSH1	
												10	VSL	
												11	VSH2	
												A [1:0] GS T VBD Level S	ransition setting for VBD Selection: ; 01b: VSH1; 1b: VSH2	
												A[1:0]	VBD Transition	
												00	LUT0	
												01	LUT1	
												10	LUT2	
												11	LUT3	
0	0	3F	0	0	1	1	1	1	1	1	End Option (EOPT)	Option for LL	JT end	
0	1		A7	A <sub>6</sub>	A <sub>5</sub>	A4	A <sub>3</sub>	A <sub>2</sub>	A1	Ao		Data bytes s	hould be set for this programmed into Waveforr	
												setting.	121 - 128	
												22h Norn		
													ce output level keep	
												prev	ious output before power of	

/W#	D/C#	Hex	D7	D6	D5	D4	D3	D2	D1	DO	Command	Descripti	on				
0	0	41	0	1	0	0	0	0	0	1	Read RAM Option	Read RA					
0	1		0	0	0	0	0	0	0	Ao		A[0]= 0 [F	POR] RAM corre	esponding	to		
												1 : Read RAM corresponding to RAM0x26		to			
0	0	44	0	1	0	0	0	1	0	0	Set RAM X - address	Specify th	ne start/en	d position	s of the		
0	1		0	0	As	A <sub>4</sub>	A <sub>3</sub>	A <sub>2</sub>	A <sub>1</sub>	A	Start / End position		ddress in t				
0	1	-	0	0	B <sub>5</sub>	B <sub>4</sub>	B <sub>3</sub>	B <sub>2</sub>	B <sub>1</sub>	Bo		address u	unit for RA	M			
U		·	U		05		03					A[5:0]: XSA[5:0], XStart, POR = 00h B[5:0]: XEA[5:0], XEnd, POR = 15h					
0	0	45	0	1	0	0	0	1	0	1	Set Ram Y- address	Specify th	ne start/en	d position	s of the		
0	1		A <sub>7</sub>	A <sub>6</sub>	A <sub>5</sub>	A <sub>4</sub>	A <sub>3</sub>	A <sub>2</sub>	A <sub>1</sub>	Ao	Start / End position	window a	ddress in t	the Y dire			
0	1		0	0	0	0	0	0	0	As	-	address u	init for RA	М			
0	1		B <sub>7</sub>	B <sub>6</sub>	B <sub>5</sub>	B <sub>4</sub>	B <sub>3</sub>	B <sub>2</sub>	B <sub>1</sub>	Bo		AI8.01. VS		Start POF	R = 000h		
0	1		0	0	0	0	0	0	0	B <sub>8</sub>	1	B[8:0]: YI	8:0]: YSA[8:0], YStart, POR = 000h 8:0]: YEA[8:0], YEnd, POR = 127h				
0	0	46	0	1	0	0	0	1		0	Auto Write RED RAM for	Auto Writ	e RED RA	M for Red	ular Patt		
0	1		A7	A	A5	A4	0	A <sub>2</sub>	A1	Ao	Regular Pattern		0h [POR]				
	1274				000000		1.143	07302404		-979-150 <b>8</b>		A[6:4]: St	1st step v ep Height, ter RAM ir to Gate	POR= 00 Y-direction	0 on		
												A[6:4]	Height	A[6:4]	Height		
												000	8	100	128		
												001	16	101	256		
												010	32	110	296		
												011	64	111	NA		
												Step of al	ep Width, I ter RAM ir to Source	X-direction			
												procession in the second	Width	A[2:0]	Width		
												000	8	100	128		
												001	16	101	176		
												010	32	110	NA		
												011     64     111       BUSY pad will output high duri operation.			NA		
														ring			

	man D/C#			D6	D5	D4	D3	D2	D1	DO	Command	Descripti	on				
				- Constants								Descripti					
0	0	47	0 A7	1 A <sub>6</sub>	0 A5	0 A4	0	1 A2	1 A1	1 A <sub>0</sub>	Auto Write B/W RAM for Regular Pattern	A[7:0] = 0	e B/W RAI 0h [POR]				
												A[7]: The 1st step value, POR = 0 A[6:4]: Step Height, POR= 000 Step of alter RAM in Y-direction according to Gate					
												A[6:4]	Height	A[6:4]	Height		
												000	8	100	128		
												001	16	101	256		
												010	32	110	296		
												011	64	111	NA		
												A[2:0]: Step Step of all according	on				
												A[2:0]	Width	A[2:0]	Width		
												000 8	100	128			
												001	16	101	176		
												010	32	110	NA		
												011	64	111	NA		
												During op high.	eration, B	USY pad	will output		
0	0	4E	0	1	0	0	1	1	1	0	Set RAM X address	Make initi	al settings	for the R	AMX		
0	1		0	0	A <sub>5</sub>	A <sub>4</sub>	Аз	A <sub>2</sub>	A1	Ao	counter		n the addr				
0	0	4F	0	1	0	0	1	1	1	1	Set RAM Y address	Make initi	al settings	for the R			
0	1		A7	A <sub>6</sub>	A <sub>5</sub>	A4	A3	A <sub>2</sub>	A1	A <sub>0</sub>	counter		n the addr				
0	1		0	0	0	0	0	0	0	As	-		0h [POR].		3 (31)		
0	1		0	0	U	U	0	U	U	A8		1					
0	0	7F	0	1	1	1	1	1	1	1	NOP	This command is an empty command; it does not have any effect on the display module. However it can be used to terminate Frame Memory Write or Read Commands.					

## 8.Optical Specifications

Measurements are made with that the illumination is under an angle of 45 degree, the detection is perpendicular unless otherwise specified

Symbol	Parameter	Conditions	Min	Тур.	Max	Units	Notes
R	White Reflectivity	White	30	35	-	%	8-1
CR	Contrast Ratio	Indoor	8:1		-		8-2
GN	2Grey Level	-		DS+(WS-DS)*n(m-1)			8-3
T update	Image update time	at 25 °C		3	-	sec	
Life		Topr		1000000times or 5years			

#### Notes:

8-1. Luminance meter: Eye-One Pro Spectrophotometer.

8-2. CR=Surface Reflectance with all white pixel/Surface Reflectance with all black pixels.

8-3 WS: White state, DS: Dark state

## 9. Handling, Safety and Environment Requirements

	Warning							
The display glass may break when it is dropped or bumped on a hard surface. Handle with care. Should the display break, do not touch the electrophoretic								
Handle with care. Should the	display break, do not touch the electrophoretic							
material. In case of contact v	vith electrophoretic material, wash with water and							
soap.								
	Caution							
Disassembling the display module can cause permanent damage and invalidates the warranty agreements.								
Observe general precautions that are common to handling delicate electronic components. The glass can break and front surfaces can easily be damaged. Moreover the display is sensitive to static electricity and other rough environmental conditions.								
	Data sheet status							
Product specification	This data sheet contains final product specifications.							
	Limiting values							
System (IEC	ccordance with the Absolute Maximum Rating							
-	re of the limiting values may cause permanent							
	are stress ratings only and operation of the							
	er conditions above those given in the							
	e specification is not implied. Exposure to limiting							
values for extended periods n	values for extended periods may affect device reliability.							
	Application information							
Where application information	n is given, it is advisory and does not form part of							
the specification.								

## 10.Reliability test

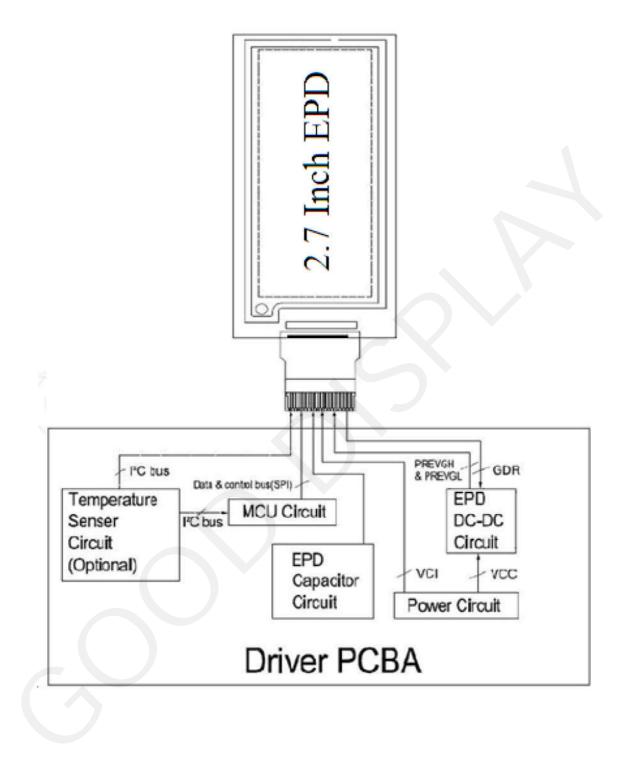
NO	Test items	Test condition
1	Low-Temperature Storage	T = -25°C, 240 h Test in white pattern
2	High-Temperature Storage	T=70° C, RH=40%, 240h Test in white pattern
3	High-Temperature Operation	T=50°C, RH=35%, 240h
4	Low-Temperature Operation	0°C, 240h
5	High-Temperature, High-Humidity Operation	T=40°C, RH=80%, 240h
6	High Temperature, High Humidity Storage	T=50° C, RH=80%, 240h Test in white pattern
7	Temperature Cycle	1 cycle:[-25° C 30min]→[+70 ° C 30 min] : 50 cycles Test in white pattern
8	UV exposure Resistance	765W/m <sup>2</sup> for 168hrs,40 °C Test in white pattern
9	ESD Gun	Air+/-15KV;Contact+/-8KV (Test finished product shell, not display only) Air+/-8KV;Contact+/-6KV (Naked EPD display, no including IC and FPC area) Air+/-4KV;Contact+/-2KV (Naked EPD display, including IC and FPC area)

### Note:

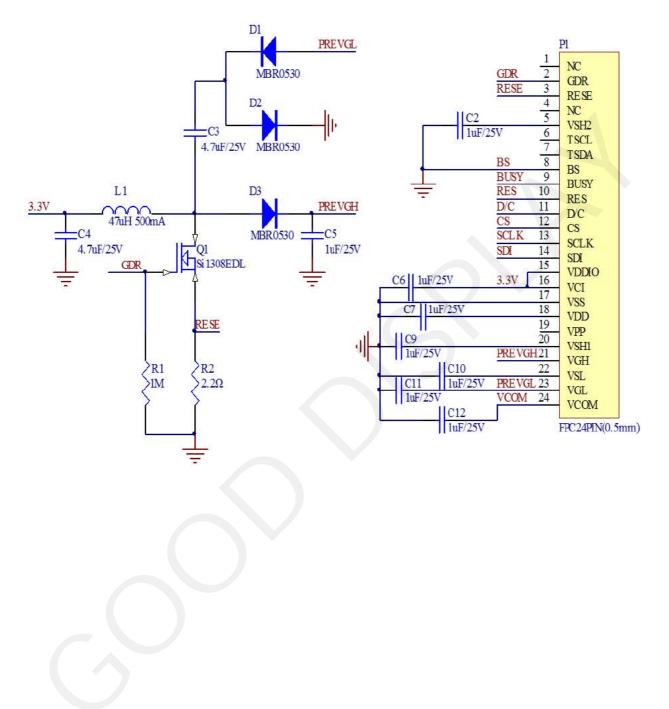
Put in normal temperature for 1hour after test finished, display performance is ok.



## 11. Block Diagram



## **12. Reference Circuit**



## **13. Matched Development Kit**

Our Development Kit designed for SPI E-paper Display aims to help users to learn how to use E-paper Display more easily. It can refresh blackwhite E-paper Display and three-color (black, white and red/Yellow) Good Display 's E-paper Display. And it is also added the functions of USB serial port, Raspberry Pi and LED indicator light ect.

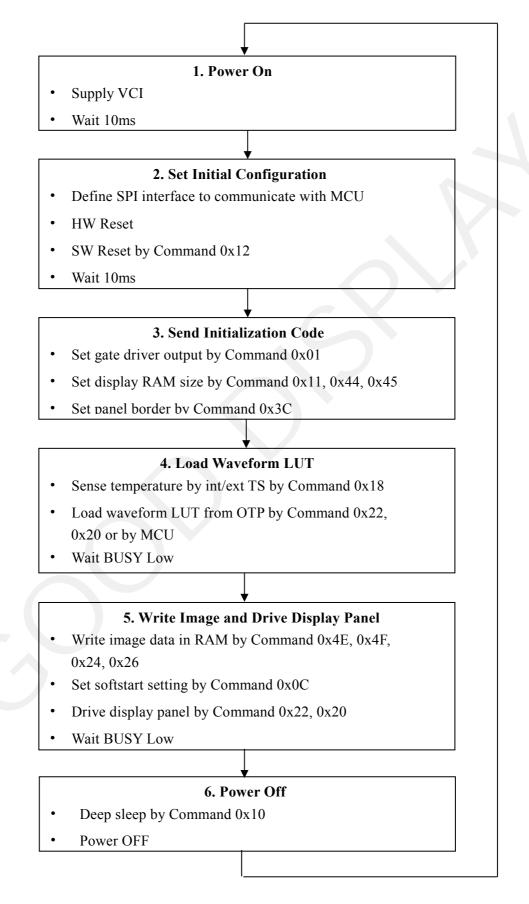
DESPI Development Kit consists of the development board and the pinboard.

More details about the Development Kit, please click to the following link:

https://www.good-display.com/product/53/

## **14.Typical Operating Sequence**

## 14.1 Normal Operation Flow



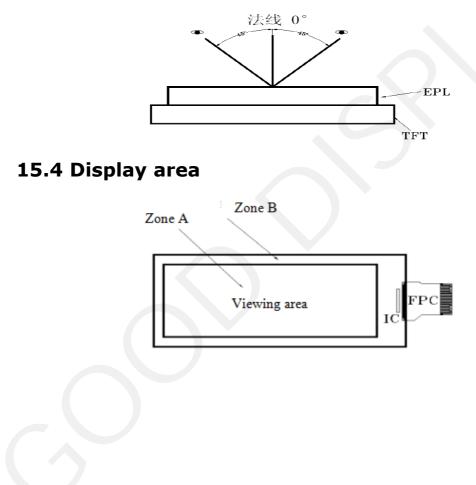
### **15.Inspection condition 15.1 Environment**

Temperature:  $25\pm3^{\circ}$ C Humidity:  $55\pm10^{\circ}$ RH

## 15.2 Illuminance

Brightness:1200~1500LUX;distance:20-30CM;Angle:Relate 30°surround.

## **15.3 Inspection method**



## **15.5 Inspection standard**

## 15.5.1 Electric inspection standard

NO.	Item	Standard	Defect level	Method	Scope
1	Display	Display complete Display uniform	MA		
2	Black/White spots	$D \le 0.25 \text{mm}$ , Allowed $0.25 \text{mm} < D \le 0.4 \text{mm} \cdot N \le 3$ , and $D = 0.4 \text{mm} \cdot N \le 3$ ,	MI	Visual inspection	
3	Black/White spots (No switch)	L $\leq$ 0.6mm, W $\leq$ 0.2mm, N $\leq$ 1 L $\leq$ 2.0mm,W $>$ 0.2mm, Not Allow L $>$ 0.6mm, Not Allow	2	Visual/ Inspection card	Zone A
4	Ghost image	Allowed in switching process	MI	Visual inspection	
5	Flash spots/ Larger FPL size	Flash spots in switching, Allowed FPL size larger than viewing area, Allowed	MI	Visual/ Inspection card	Zone A Zone B
6	Display wrong/Missing	All appointed displays are showed correct	MA	Visual inspection	Zone A
7	Short circuit/ Circuit break/ Display abnormal	Not Allow			

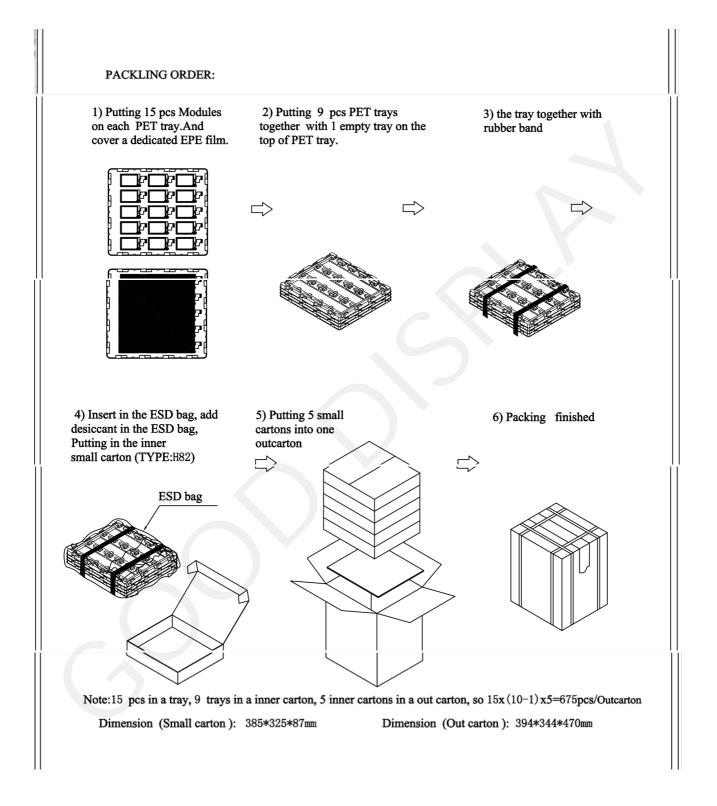


## **15.5.2 Appearance inspection standard**

NO.	Item	Standard	Defect level	Method	Scope
1	B/W spots /Bubble/ Foreign bodies/ Dents	$L \rightarrow U$ $D = (L+W)/2$ $D \le 0.25 \text{ mm}, \text{ Allowed}$ $0.25 \text{ mm} < D \le 0.4 \text{ mm}, \text{ N} \le 3$ $D > 0.4 \text{ mm}, \text{ Not Allow}$	MI	Visual inspection	Zone A
2	Glass crack	Not Allow	MA	Visual	Zone A Zone B
3	Dirty	Allowed if can be removed	MI	/ Microscope	Zone A Zone B
4	Chips/Scratch/ Edge crown	x $X \le 3$ mm, Y $\le 0.5$ mmAnd without affecting the electrode is permissible y $y$ $y$ $y$ $y$ $y$ $y$ $y$ $y$ $y$	MI	Visual / Microscope	Zone A Zone B
5	TFT Cracks	Not Allow	MA	Visual / Microscope	Zone A Zone B
6	Dirty/ foreign body	Allowed if can be removed/ allow	MI	Visual / Microscope	Zone A / Zone B
7	FPC broken/ Goldfingers xidation/ scratch	Not Allow	MA	Visual / Microscope	Zone B

8	TFT edge bulge /TFT chromatic aberration	TFT edge bulge: $X \leq 3$ mm, $Y \leq 0.3$ mm Allowed TFT chromatic aberration :Allowed	MI	Visual / Microscope	Zone A Zone B
9	PCB damaged/ Poor welding/ Curl	PCB (Circuit area) damaged Not Allow PCB Poor welding Not Allow PCB Curl≤1%			
10	Edge glue height/ Edge glue bubble	Edge Adhesives H≤PS surface (Including protect film) Edge adhesives seep in≤1/2 Margin width Length excluding Edge adhesives bubble: bubble Width ≤1/2 Margin width; Length ≤0.5mm <sub>☉</sub> n≤5	MI	Visual / Ruler	Zone B
11	Protect film	Surface scratch but not effect protect function, Allowed		Visual Inspection	
12	Silicon glue	Thickness $\leq$ PS surface(With protect film): Full cover the IC; Shape: The width on the FPC $\leq$ 0.5mm (Front) The width on the FPC $\leq$ 1.0mm (Back) smooth surface,No obvious raised.	MI	Visual Inspection	
13	Warp degree (TFT substrate)	t≤2.0mm	MI	Ruler	
14	Color difference in COM area (Silver point area)	Allowed		Visual Inspection	

## 16. Packing



### **17.** Precautions

- (1) Do not apply pressure to the EPD panel in order to prevent damaging it.
- (2) Do not connect or disconnect the interface connector while the EPD panel is in operation.
- (3) Do not touch IC bonding area. It may scratch TFT lead or damage IC function.
- (4) Please be mindful of moisture to avoid its penetration into the EPD panel, which may cause damage during operation.
- (5) If the EPD Panel / Module is not refreshed every 24 hours, a phenomena known as "Ghosting" or "Image Sticking" may occur. It is recommended to refreshed the ESL /EPD Tag every 24 hours in use case. It is recommended that customer ships or stores the ESL / EPD Tag with a completely white image to avoid this issue
- (6) High temperature, high humidity, sunlight or fluorescent light may degrade the EPD panel's performance. Please do not expose the unprotected EPD panel to high temperature, high humidity, sunlight, or fluorescent for long periods of time.
- (7) For more precautions, please click on the link: https://www.good-display.com/news/80.html